EXPRESS MAIL NO. EV530945524US Sheet 1 of 1 U.S. DEPARTMENT OF COMMERCE PATENT AND TRUDEMARK OFFICE FORM PTO-1449 ATTY. DOCKET NO. APPLICATION NO. (REV.7-80) 854063.738 10/719,650 APPLICANTS INFORMATION DISCLOSURE STATEMENTL 1 2 2005 Andrea Bellini et al. (Use several sheets if necessary FILING DATE GROUP ART UNIT November 21, 2003 2827 TENT DOCUMENTS *EXAMINER DOCUMENT NUMBER FILING DATE DATE NAME CLASS SUBCLASS INITIAL IF APPROPRIATE TNI AA 5,847,994 12/08/98 Motoshima et al. 365 185.11 5,847,998 12/08/98 Van Bushkirk ΑB 365 185.33 AC 5,894,437 04/13/99 Chang et al. 365 185.13 AD 6,016,270 01/18/00 Thummalapally et al. 365 185.11 TNI 2002/0131301 09/19/02 Elmhurst 365 185.11 ΑF AG AH ΑI ΑJ FOREIGN PATENT DOCUMENTS DOCUMENT TRANSLATION DATE COUNTRY NUMBER YES TNI 0 745 995 A1 12/04/96 EP AM AN OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.) Pathak, B., et al., "A 1.8V 64Mb 100Mhz Flexible Read While Write Flash Memory," in Proceedings of the IEEE International Solid-State Circuits Conference, Piscataway, NJ, February 5-7, 2001, pp. 32-33, 424-425.

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Initial if reference considered, whether or not criteria is in conformance with MPEP 609. Draw line through citation if not in

conformance and not considered. Include copy of this form with next communication to applicant(s).